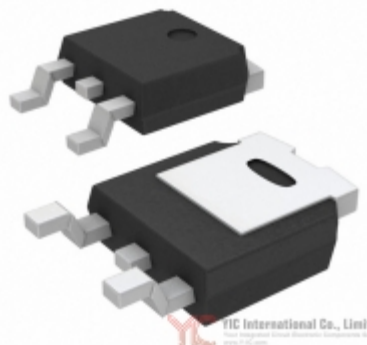









	<h2>STD1HN60K3</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">STD1HN60K3</a>
	<b>Hersteller / Marke:</b>	<a href="#">STMicroelectronics</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 600V 1.2A DPAK
<b>Datenblätter:</b>	 <a href="#">STD1HN60K3.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 9728 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	<a href="#">STD1HN60K3</a>
Hersteller	<a href="#">STMicroelectronics</a>
Beschreibung	MOSFET N-CH 600V 1.2A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	9728 pcs Stock
Serie	SuperMESH3™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	27W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	1.2A (Tc)
Rds On (Max) @ Id, Vgs	8 Ohm @ 600mA, 10V
VGS (th) (Max) @ Id	4.5V @ 50µA
Gate Charge (Qg) (Max) @ Vgs	9.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	140pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)


















































STD1HN60K3 ist neu im Original, Suche STD1HN60K3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD1HN60K3 STMicroelectronics mit Garantie und Vertrauen.  
Anfrage STD1HN60K3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>STD19NE06T4-TR</b> ST STD19NE06T4-TR ST	 <b>STD1HNC60T4G</b> ST STD1HNC60T4G ST	 <b>STD19NE06LT4</b> ST STD19NE06LT4 ST	 <b>STD1HNC60T4</b> STMicroelectronics MOSFET N-CH 600V 2A DPAK
 <b>STD19NF20</b> STMicroelectronics MOSFET N-CHANNEL 200V 15A DPAK	 <b>STD19NE06L</b> ST STD19NE06L ST	 <b>STD19NF06L</b> STMicroelectronics MOSFET N-CH 60V DPAK	 <b>STD1LNC60</b> ST ST TO-252

### heiße Teile

Mehr

 STD181GK18	 STD181GK18B	 STD1862Y	 STD18GK08	 STD18GK08B
 STD18GK12	 STD18GK12B	 STD18GK14	 STD18GK14B	 STD18GK16
 STD18GK16B	 STD18GK18	 STD18GK18B	 STD18N55M5	 STD18N65M5
 STD18NF03L	 STD18NF03LT4	 STD18NF25	 STD1955NL	 STD19NE06
 STD19NE06L	 STD19NE06LT4	 STD19NE06T4-TR	 STD19NF06L	 STD19NF20
 STD1HNC60	 STD1HNC60-1	 STD1HNC60T4	 STD1HNC60T4G	 STD1LNK60Z
 STD1LNK60Z-1	 STD1N20SPY-TR	 STD1NB40	 STD1NB52	 STD1NB60T4
 STD1NB80	 STD1NB80-1	 STD1NB80-T4	 STD1NB80T4	 STD1NC60
 STD1NC60-1	 STD1NK60	 STD1NK60-1	 STD1NK60T4	 STD1NK60Z
 STD1NK80	 STD1NK80z	 STD1NK80Z-1	 STD1NK80ZT4	 STD20N03LT4

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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